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Hole injection dynamics from two structurally related Ru–bipyridine complexes into NiO_x is determined by the substitution pattern of the ligands†

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The dyes bis[2,2′-bipyridine][4,4′-dicarboxy-2,2′-bipyridine]ruthenium(II) dihexafluorophosphate, [Ru(bpy)₂dcb]-(PF₆)₂ (**Ru1**), and tris[4,4′-bis(ethylcarboxy)-2,2′-bipyridine]ruthenium(II) dihexafluorophosphate, [Ru(dceb)₃](PF₆)₂ (**Ru2**), attached to NiO_x nanoparticle films were investigated using transient absorption and luminescence spectroscopy. In acetonitrile solution the dyes reveal very similar physical and chemical properties, *i.e.* both dyes exhibit comparable ground state and long-lived, broad excited state absorption. However, when immobilized onto a NiO_x surface the photophysical properties of the two dyes differ significantly. For **Ru1** luminescence is observed, which decays within 18 ns and ultrafast transient absorption measurements do not show qualitative differences from the photophysics of **Ru1** in solution. In contrast to this the luminescence of photoexcited **Ru2** on NiO_x is efficiently quenched and the ultrafast transient absorption spectra reveal the formation of oxidized nickel centres overlaid by the absorption of the reduced dye **Ru2** with a characteristic time-constant of 18 ps. These findings are attributed to the different localization of the initially photoexcited state in **Ru1** and **Ru2**. Due to the inductive effect (−I) of the carboxylic groups, the lowest energy excited state in **Ru1** is localized on the dicarboxy-bipyridine ligand, which is bound to the NiO_x surface. In **Ru2**, on the other hand, the initially populated excited state is localized on the ester-substituted ligands, which are not bound to the semiconductor surface. Hence, the excess charge density that is abstracted from the Ru-ion in the metal-to-ligand charge-transfer transition is shifted away from the NiO_x surface, which ultimately facilitates hole transfer into the semiconductor.

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Introduction

The immobilization of photosensitizers and photocatalysts onto semiconductor nanoparticle films is a promising route towards the combination of molecular components (and with it the potential of molecular design) with the electronic and photo-physical properties and the structural stability of solid materials. One option to exploit the benefits of molecularly sensitized

semiconductors is the development of photo-catalytically active electrode materials.^{1,2} In these devices, the semiconductors either play the role of antenna systems in enhancing the effective absorption cross section of the attached photocatalysts or they function as acceptor materials for electrons (n-type semiconductor) or holes (p-type semiconductors). In the latter function, the oxidized or reduced sensitizers can act as oxidation or reduction catalysts, respectively.^{3–7} However, arguably the most important example is the development of dye-sensitized solar cells (DSCs).⁸ After the seminal report on this technology by Grätzel and co-workers the concept of DSCs has developed from an interesting scientific concept into a promising technology to produce low-cost, low-weight solar cells for integration into buildings and for use as decentralized electrical power devices. The first DSCs reported were based on TiO₂ photoanodes sensitized with Ru^{II}-complexes.⁹ Since then a variety of photoanode materials has been reported and extensive research has been carried out to substitute the rare-earth containing dyes by sensitizers not containing expensive metals.¹⁰ Here, the most promising candidates contain tri-phenylamine moieties.^{11–13} In addition

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to optimizing the photoanode, tandem DSCs can be designed, which combine photoanodes with photocathodes thereby increasing the accessible open-circuit voltage of the devices.^{14,15} Research on photocathode materials is currently almost exclusively based on NiO_x as a p-type semiconductor material, since it is inexpensive, accessible and exhibits the appropriate electrochemical properties.¹⁶

A variety of other design-parameters impact the overall performance of a DSC or a photocatalytic electrode, including the overall long-term stability under operating conditions and the choice of the redox mediator. Particular emphasis is put on studies of the kinetics of the photoinduced electron or hole injection as this presents the initial step in the overall charge-separation process. For TiO₂-surfaces functionalized with molecular sensitizers the initial charge injection from the photoexcited dye into the conduction band of the semiconductor can occur as rapid as sub-50 fs.⁸ In addition to this, charge injection from non-thermally relaxed, vibrational hot excited states has been observed on the ps timescale and these are responsible for up to 40% (RuN₃|TiO₂) of the overall injected charges.¹⁷ In the case of RuN₃ [*cis*-diisothiocyanato-bis(2,2'-bipyridyl-4,4'-dicarboxylic acid) ruthenium(II)] it has been established that interligand hopping can critically impact the overall charge transfer efficiency by determining the rate of the electron injection from thermally relaxed ³MLCT (triplet metal-to-ligand charge-transfer) states into the conduction band of TiO₂.¹⁸ This points to the fact that localization of the initially photoexcited MLCT state within the molecular framework and its orientation with respect to the semiconductor surface plays an important role in optimizing the function of molecular sensitizers for DSCs.

Several studies were performed to transfer the advantageous properties of Ru dyes, when used to sensitize n-type semiconductors, to p-type NiO_x photoelectrodes. These advantages are in particular the long-lived photoexcited charge-transfer state (³MLCT), the chemical stability, and the tunability of the molecular and electronic structure. In order to understand hole injection dynamics from Ru-type dyes into NiO_x nanoparticle films, different dye systems have been investigated. For example, studies on cyclometalated Ru-complexes with different spacer lengths were performed and these show hole injection into NiO_x within 10 and 50 ps depending on the number of phenylene-spacer units and a multi-exponential recombination from the 100 ps to ns regime.¹⁹ A Ru^{II}-naphthalenediimide dyad has been shown to form the charge-separated state [NiO(h⁺)-Ru^{II}-NDI⁻] within 1.1 ps.²⁰ A study dealing with a structurally more complex Ru-based donor-acceptor photosensitizer, where an electron-accepting group, 4-nitronaphthalene-1,8-dicarboximide (NMI), is attached to the phenanthroline of [Ru(dcb)₂(NMI-phen)]²⁺, reports a fast injection in ~1 ps—a value that is based on indirect spectroscopic evidence.²¹ Aside from spectroscopic studies on Ru dyes on NiO_x surfaces the injection of electrons from NiO_x nanoparticles into organic dyes has been studied and is found to be generally fast (~1 ps).^{15,22–27}

The existing studies on Ru-sensitizer functionalized NiO_x surfaces generally deal with structurally more complex Ru dyes but – to the best of our knowledge – no measurements on

Ru(bpy)₃²⁺-type 'building blocks' were reported so far. In this contribution, the dyes bis[2,2'-bipyridine][4,4'-dicarboxy-2,2'-bipyridine]ruthenium(II) dihexafluorophosphate, [Ru(bpy)₂dcb](PF₆)₂ (**Ru1**), and tris[4,4'-bis(ethylcarboxy)-2,2'-bipyridine]ruthenium(II) dihexafluorophosphate, [Ru(dceb)₃](PF₆)₂ (**Ru2**), were chosen and spectroscopically studied when attached to NiO_x nanoparticle films. The purpose of this study is to investigate the influence of the different ligands on the hole injection rate. The redox potentials of both dyes are comparable ($E_{\text{III/II}}^{\text{Ru1}} = 1.31 \text{ V}$,²⁸ $E_{\text{III/II}}^{\text{Ru2}} = 1.30 \text{ V}$ ²⁹) and match the valence band potential of NiO_x with 0.37 V.³⁰ Thus, hole injection is energetically possible in both cases.

In this study ultrafast transient absorption spectroscopy is utilized to unravel the hole injection from two Ru^{II}-bipyridine-derived dyes into nanoparticulate NiO_x films. The focus on this study is on the sub-100 ps dynamics of hole injection, *i.e.* a kinetic window which has not been as intensively exploited as for example the ns- to μs-range. While the latter is of particular interest for the recombination kinetics, the sub-100 ps processes are relevant to describe the forward reaction, *i.e.* the initial charge separation across the molecular-semiconductor interface. Mechanistic differences in the photophysics of the dye-sensitized surfaces are discussed and substantiated by attenuated total reflection-Fourier transform infrared spectroscopy (ATR-FTIR) measurements showing information on binding geometries.

Experimental section

Investigated dyes

The two ruthenium dyes bis[2,2'-bipyridine][4,4'-dicarboxy-2,2'-bipyridine]ruthenium(II) dihexafluorophosphate, [Ru(bpy)₂dcb](PF₆)₂ (**Ru1**), and tris[4,4'-bis(ethylcarboxy)-2,2'-bipyridine]ruthenium(II) dihexafluorophosphate, [Ru(dceb)₃](PF₆)₂ (**Ru2**), were investigated on NiO_x. Both dyes were available from earlier studies.^{31,32}

Dye-sensitized NiO_x surfaces

The synthesis of the NiO_x surfaces was performed with minor alterations of the protocol described in the literature.^{33,34} The polymer-NiCl₂ solution was spin coated onto the glass substrate and burned in a furnace at 450 °C for 30 min.³⁵ The NiO_x films used here were produced by a second spin-coating/burning step.³⁴ After cleaning the NiO_x surface with deionized water (MilliQ) the films were soaked in acetonitrile-dye solution (10⁻³ M) for 24 h to sensitize the NiO_x nanoparticles.

UV-vis

All UV-vis measurements were carried out on a Jasco V-530 spectrometer in aerated samples.

ATR-FTIR

Measurements were carried out on a Perkin Elmer Spectrum 100 FT-ATR.

‡ All potentials vs. NHE.



Transient absorption

The setup for transient absorption spectroscopy has been described previously.^{36,37} The pump pulses (pulse duration below 150 fs) to excite the Ru dyes were centered at 480 nm and were delivered by a TOPAS-C. A supercontinuum served as a broad-band probe. The pump-pulse energy was 2 μ J, while typical probe intensities fall into the range of hundred nJ. For a kinetic analysis the differential optical densities recorded as a function of the delay time and the probe wavelength were chirp corrected and subsequently subjected to a global fit routine using a sum of exponential functions for data analysis.³⁸ The wavelength-dependent pre-exponential factors represent the so called decay-associated spectra (DAS) connected with the kinetic components. In order to avoid prominent contributions from coherent artifacts,^{39,40} the pulse-overlap region was excluded in the data fitting procedure.

Luminescence lifetime

For emission lifetime measurements a Hamamatsu HPDTA streak camera is employed. A Ti:sapphire laser (Tsunami, Newport Spectra-Physics GmbH) is used as the light source. The repetition rate of the laser is reduced to 400 kHz using a pulse selector (Model 3980, Newport Spectra-Physics GmbH). Afterwards the fundamental beam of the oscillator is frequency doubled to yield the 375 nm pump beam. The thin film sample is placed in a *ca.* 45° angle with respect to the excitation beam and emission light is collected from the back side of the sample in 90° geometry. The emission is detected by the streak camera *via* a CHROMEX spectrograph that images a 140 nm broad spectral window on the entrance slit of the streak scope. The experimental response of the streak camera is determined by the scattering signal of a blank NiO_x-nanoparticle film. The deconvolution of the experimental response function and the luminescence decay is done in GNU Octave.⁴¹

Results and discussion

Nanoporous NiO_x double films were prepared from NiCl₂ in water-ethanol mixed solution using the commercially available triblock co-polymer F108 as a template.^{33,34} After sensitization with **Ru1** and **Ru2** the NiO_x surfaces were investigated using attenuated total reflection-Fourier transform infrared spectroscopy (ATR-FTIR) in order to unravel the binding geometries of the complexes on the surface (see Fig. 1). In the carboxy region there are two important features: a broad band at 1700 cm⁻¹ and a doublet at about 1600 cm⁻¹. According to the literature, both are related to the carboxylic function of the bipyridine ligands.^{42,43} The band at 1700 cm⁻¹ corresponds to the $\nu(\text{C=O})$ of the acid/ester and the double band centred at 1600 cm⁻¹ is connected to stretching vibrations $\nu(\text{COO})$ of the carboxylic function bound to the NiO_x surface. Consequently, the following can be deduced: (1) for both **Ru1** and **Ru2** the intensity of the IR-bands increases and the bands at 1600 cm⁻¹ appear broadened (relative to the region at 1700 cm⁻¹), which indicates binding of both dyes to the NiO_x surface (see Fig. 1e \rightarrow c, d \rightarrow b). (2) Furthermore, in the case of **Ru1**, the $\nu(\text{C=O})$ band of the

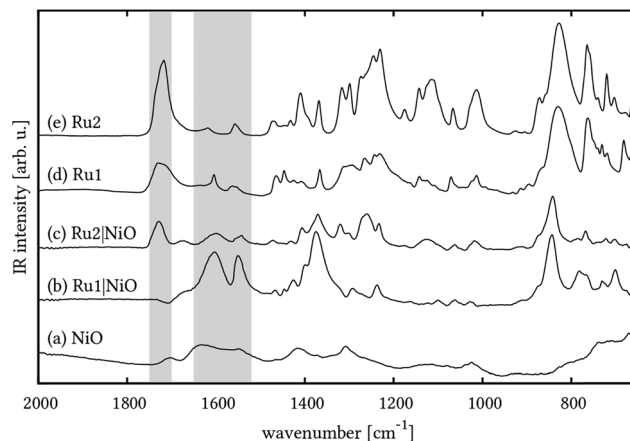


Fig. 1 ATR-FTIR spectra of blank NiO_x (a), **Ru1** on NiO_x (b), **Ru2** on NiO_x (c), pure **Ru1** (d), and pure **Ru2** (e). The spectra in (b) and (c) are calculated by subtraction of the NiO_x spectrum in (a) from the raw spectra.

acid/ester at 1700 cm⁻¹ completely vanishes. This implies that all anchor groups are bound to the NiO_x surface in **Ru1** (see Fig. 1d \rightarrow b). (3) Upon sensitizing NiO_x with **Ru2**, the band at 1700 cm⁻¹ remains unchanged in its position. Thus, free unbound ester groups are present. Unfortunately, in the case of **Ru2** the number of anchor groups bound to NiO_x cannot be concluded from these spectra, but speculatively it is two or three, which would be in good agreement with the literature.²⁸ This implies that at least one ligand in **Ru2** is not bound to the NiO_x.

These findings are of importance for the interpretation of the transient absorption spectroscopy unravelling the ultrafast dynamics and hole injection. The results of these measurements are compared to the respective measurements of the dyes in acetonitrile solution and to the ground-state absorption spectra (see Fig. 2). The latter are very similar for both investigated sensitizers and exhibit the prominent MLCT band at *ca.* 460 nm that is typical for ruthenium bipyridine dyes.

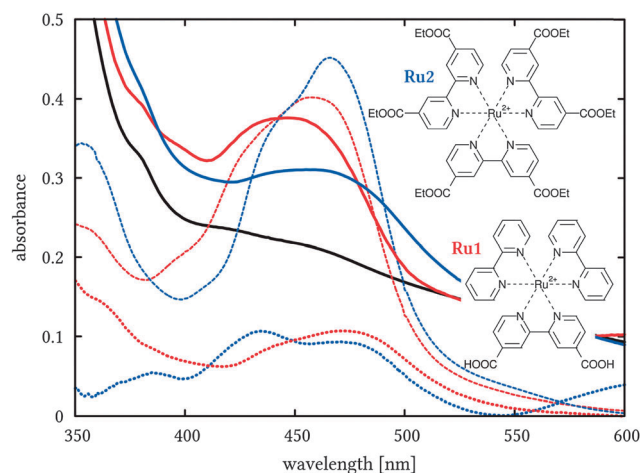


Fig. 2 Absorption spectra of **Ru1** (red) and **Ru2** (blue) in acetonitrile (dashed) and on NiO_x (solid, thick) with structural formulae. The spectrum of the blank NiO_x is shown in black and difference spectra of the dyes on NiO_x and blank NiO_x are visualised with dotted lines.



To study the ultrafast excited state dynamics of the complex in acetonitrile solution and on NiO_x surfaces the systems were excited at 480 nm and thus in the $^3\text{MLCT}$ band. Generally, the recombination of the interfacial charge-separated state $[\text{NiO}_x(\text{h}^+)-\text{Ru}^{\text{II}}-\text{bpy}^{\cdot-}]$ occurs on long time-scales, which exceed the temporal window of the set-up used here (~ 2 ns),²⁰ e.g. in $\text{Ru}(\text{dcb})_3^{2+}$ attached to NiO_x nanoparticles recombination occurs within 5 μs .²¹ Thus, this contribution focuses on the photoinduced ultrafast processes in the photoexcited dye and the hole injection dynamics to the NiO_x , the subsequent fate of the injected holes is not considered.

In solution negative signal contributions dominate the spectrum at wavelengths shorter than 530 nm and are accompanied by a broad, rather structureless excited-state absorption band at longer wavelength as commonly observed for ruthenium polypyridine dyes.^{19,44} Under these conditions and timescales both **Ru1** and **Ru2** show little or no decay of the excited state back to the ground state. Thus, only one long-lived, prominent component ($\gg 2$ ns) describing the decay of the differential absorption signal results from the global fit of the transient absorption data (see ESI† and Fig. 4A and B). This finding reflects the long excited-state lifetimes typical for Ru-bipyridine complexes.⁴⁵

Light-absorption by **Ru1** on NiO_x leads to spectral features resembling those for **Ru1** in solution (see Fig. 3A) and results in multi-exponential decay kinetics observable over the entire range of probe-wavelengths. The multi-exponential decay can be described by the presence of three distinct kinetic components, i.e. $\tau_1 = 1.9$ ps, $\tau_2 = 31$ ps and $\tau_3 = 460$ ps, and an additional component reflecting the long-lived photoinduced absorption features of the sample (see Fig. 4C). The overall shape of the transient absorption spectrum with its maximum at about 600 nm barely changes during the temporal evolution of the signal within the experimentally accessible range of delay times; below and above 530 nm negative and positive ΔOD signals are observed, respectively (see Fig. 3A), and the relative decay for both negative and positive signals is the same, i.e. between 1 ps and 1.6 ns the signal intensity decreases to about 30% (see kinetic traces in the ESI†).

The photoinduced dynamics of immobilized **Ru2** (see Fig. 3B) are markedly different from those observed for **Ru1** on NiO_x surfaces. The transient spectrum of **Ru2** in NiO_x recorded 1 ps after photoexcitation is characterized by negative absorbance changes below 535 nm and a maximum of the broad photo-induced absorption band at about 610 nm. These features are in agreement with the absorption of $^3\text{MLCT}$ -states in related complexes, in which the negative differential absorption is attributed to ground-state bleaching and the positive absorption band at roughly 600 nm to a ligand-to-metal charge-transfer band.⁴⁶ With increasing delay-times the $\Delta\text{OD} = 0$ -point shifts to shorter wavelength, i.e. from 540 nm at 0.1 ps to about 510 nm at >1000 ps (see Fig. 3). This dynamic shift of the $\Delta\text{OD} = 0$ -point is accompanied by the transient formation of a pronounced excited-state absorption maximum at 535 nm. The intensity of this band peaks at 60 ps and afterwards decays to form a rather unstructured long-lived differential absorption spectrum. The long-lived transient absorption spectrum shows a photoinduced absorption in the entire range of probe-wavelengths accessible in this study with a residual maximum at 535 nm. This behaviour is qualitatively different from the photoinduced dynamics of **Ru2** in solution (see Fig. 4B and D). While the initial differential-absorption changes of **Ru2** on NiO_x resemble the features of the early-time transient-absorption spectrum of **Ru2** in solution this behaviour changes considerably for longer times (>1 ps) due to the evolution of the maximum at 535 nm. These qualitative differences in the appearance of the photoinduced dynamics when comparing **Ru2** in solution with **Ru2** anchored onto a NiO_x surface reflect the significant impact of the p-type semiconductor on the excited-state kinetics of the dye.

Thus, the central feature in the transient absorption spectra, which reflects this different photophysics, is the appearance of the transiently populated excited-state absorption band at 535 nm (see Fig. 3B). On one hand, the position of this band can be assigned to the absorption of oxidized Ni-centres at the surface of the semiconductor, as previously shown in a related system.^{21,47} On the other hand, the electrochemically reduced dye **Ru2** shows a ground state absorption at 527 nm.²⁹ The two

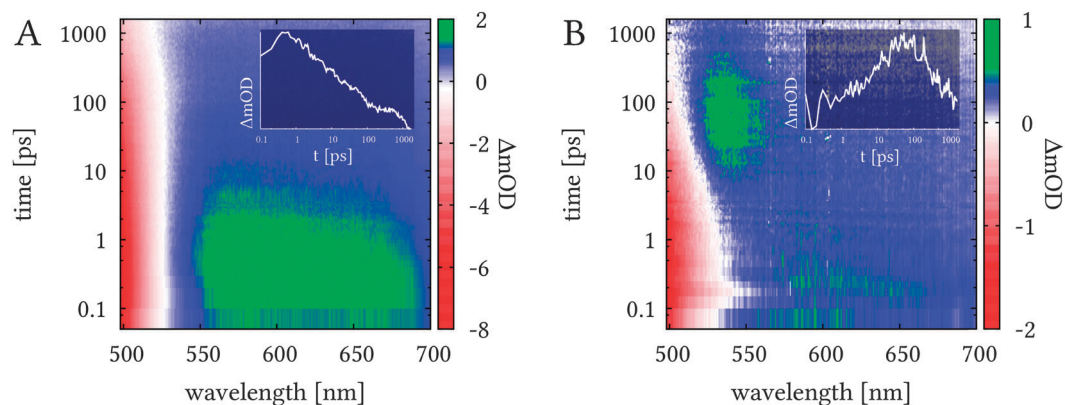


Fig. 3 Transient absorption data maps of **Ru1** (A) and **Ru2** (B) on NiO_x . The differential optical density is colour coded: positive absorption is blue and green, negative absorption red. White areas indicate $\Delta\text{OD} = 0$, which is time dependent in **Ru2**, i.e. zero shifts from 535 nm at 1 ps to about 510 nm at 1000 ps (B). The insets show the temporal evolution of the signal at 550 nm on a logarithmic scale.



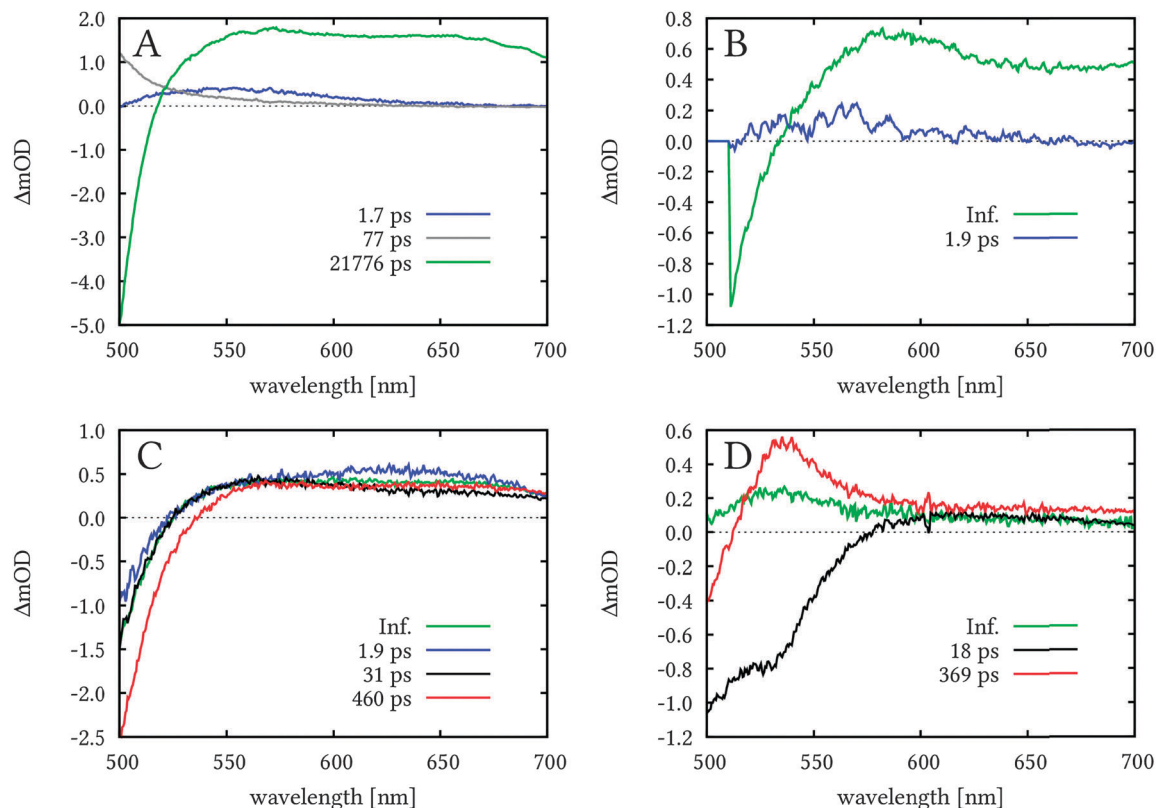


Fig. 4 Decay associated spectra (DAS) of **Ru1** in ACN (A), **Ru2** in ACN (B), **Ru1** on NiO_x (C), **Ru2** on NiO_x (D).

species, *i.e.* reduced **Ru2** and oxidized Ni, may contribute to the transient absorption spectrum, but both are indicative of the hole injection from the photoexcited **Ru2** to the valence band of the NiO_x .²⁵ Notably the formation of a photoinduced transient with the absorption here, which is indicative of hole injection, is not observed for **Ru1** on the NiO_x surface.

In order to quantitatively analyze the photoinduced kinetics, a multiexponential model was fit globally to the transient absorption data. By judging the systematic residuals (see ESI†) a bi-exponential function including an offset to reflect any long-lived component was found to be sufficient to fit the data. The resultant time-constants, which describe the photophysics of **Ru2** on NiO_x , are $\tau_1 = 18$ ps and $\tau_2 = 370$ ps. The corresponding decay-associated spectra (DAS) are displayed in Fig. 4B. The spectral characteristics of the 18 ps component indicate a decay of the structureless excited-state absorption at wavelength longer than 570 nm, which is accompanied by fading contributions from ground-state bleach centred at around 510 nm. Notably, a shoulder at 535 nm is visible in the negative differential absorption band of the 18 ps component. The latter spectral feature exactly correlates with the positive differential absorption feature in the DAS associated with the 370 ps component. This indicates that the hole injection, associated with the 535 nm photoinduced absorption, occurs with the characteristic time-constant τ_1 . The decay of the respective absorption band is described by τ_2 . However, it should be noted that the 370 ps recombination is only partial and some are still observed at long delay-times as can be deduced from

the weak transient absorption peak below 550 nm seen in the long-lived component.

The hole injection rate (approx. 0.05 ps^{-1}) reported here is relatively slow compared to the often found ~ 100 fs injection dynamics on NiO_x . Nevertheless, the injection time-constant reported here matches the slowest injection time-constants described in the literature, which describe time-scales of tens of picoseconds.^{8,20,26,48} Furthermore, the red tail of the long-lived absorption (see Fig. 4D) correlates with the spectral features of excited **Ru2** molecules but has also been observed in spectro-electrochemical UV/vis-absorption spectroscopy experiments on NiO_x nanoparticles.⁴⁷ This finding indicates that after completion of the ultrafast photophysics a fraction of the initially photoexcited **Ru2** ensemble remained in the long-lived triplet state (luminescence lifetime $\tau_{\text{lum}} = 2.1 \mu\text{s}$ for **Ru2** in degassed ACN solution²⁹) and does not contribute to the fast photoinduced hole injection processes.

Time-resolved luminescence measurements were carried out in order to further detail the luminescence properties and in particular the remaining long-lived transient absorption of the dye-sensitized NiO_x surfaces. The luminescence spectra (see Fig. 5D) are indicative of only very weak luminescence for **Ru2** on NiO_x – centred in the range between 580 and 650 nm. In contrast, stronger luminescence is observed in the case of **Ru1** on NiO_x . Here, a spectral maximum centred at about 650 nm is visible. Both findings are consistent with the results from the transient absorption spectra discussed above but shed additional light on the molecular origin of the long-lived transient



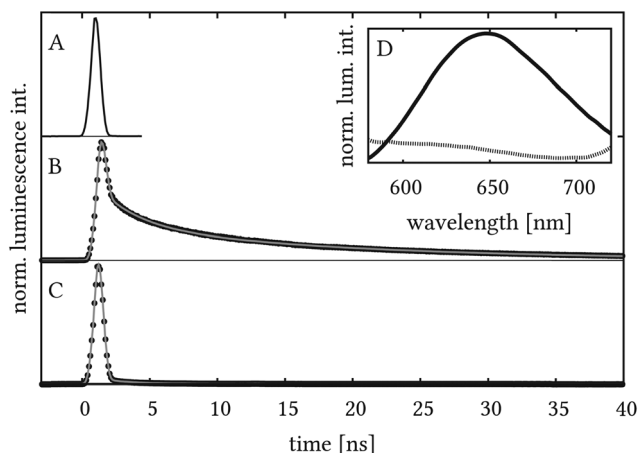
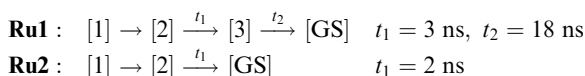


Fig. 5 Time-resolved luminescence measurements showing instrumental response (blank NiO_x) (A), **Ru1** (B) and **Ru2** (C) on NiO_x . Experimental data in B and C are indicated by black dots while the multi-components fit is shown as a gray solid line. The inset D shows the mean data for all times yielding a spectrum for **Ru1** (solid line) that mainly consists of contributions from the emission and a spectrum that represents the instrumental response function for **Ru2** (dotted line).

absorption signals observed for long delay times (> 2 ns) in the transient-absorption experiments. The time-resolved emission data (see Fig. 5) of **Ru1** were fitted best with a three-component model, while that of **Ru2** was fitted with a two-component model (see Scheme 1).



Scheme 1 Fitting models/reaction schemes for the time-resolved luminescence data for both dyes.

Species [1] is produced within the experimental response. Species [2] and [3] represent the luminescent species. For both systems a fast decay of the luminescence with a characteristic time-constant t_1 in the order of a few ns is observed. The main difference between the investigated systems is the long-lived component [3] which is only present in the case of **Ru1** and decays with a characteristic time-constant of 18 ns. The luminescence data can be understood in the context of photo-induced hole injection into the semiconductor from **Ru2**, which efficiently quenches the luminescence of the dye. As **Ru1** does not inject holes into NiO_x , the luminescence cannot be quenched by this process. Instead, a luminescence-decay with a lifetime of 18 ns, which falls into the range of other ruthenium dyes on semiconductor surfaces, is observed. It should be noted that the luminescence lifetime of **Ru1** in degassed acetonitrile is 490 ns.⁴⁹

The experimental results presented in this study provide clear evidence for the fundamentally different photophysics of **Ru1** and **Ru2** on NiO_x , which is initially rather surprising since the chemical structures of the dyes are overall very similar. According to the ATR-FTIR data presented here, the most probable binding geometry is realized *via* the carboxylic groups which is in good agreement with the literature.⁵⁰ The difference

between **Ru1** and **Ru2** on NiO_x is that the ligands not bound to the NiO_x surface are bipyridine in the case of **Ru1** and at least on the ligand of di-carboxy-ethyl bipyridine for **Ru2**. The impact of the ester groups on the electronic structure of bipyridine ligands in Ru^{II} complexes is well known from the literature investigating the light-switch effect in Ru dyes: it could be shown that the introduction of carboxy-methyl groups into the bipyridine ligands lowered the $^3\text{MLCT}$ state localized on the bipyridine. As a consequence the excess charge density upon MLCT-excitation was not transferred to the dipyrrophenazine ligand anymore, and hence the characteristic light-switch effect of Ru-dppz complexes was prohibited.⁵¹ The experimental results presented here indicate a similar effect of the carboxy-ethyl groups in **Ru2**. This means that the excitation after intersystem crossing and thermal relaxation is located on the ligands that are not bound to the NiO_x surface. Thus, an electron transfer from the semiconductor surface is not hindered by the localized excitation. This scenario is schematically presented in Fig. 6, which summarizes the different excitation pathways for the two dyes. After an initial excitation (I), **Ru1** relaxes to a $^3\text{MLCT}$ state that is located on the ligand, which is bound to NiO_x (IIb). From here, radiative decay to the ground state (IVb) takes place as evidenced by time-resolved luminescence measurements. In case of **Ru2**, the intersystem crossing and thermal relaxation lead to a $^3\text{MLCT}$ state that is located on a ligand that is not bound to the NiO_x surface (IIa). The effect of the inverted order of the $^3\text{MLCT}$ states is due to the $-I$ effect of the carboxy-ethyl

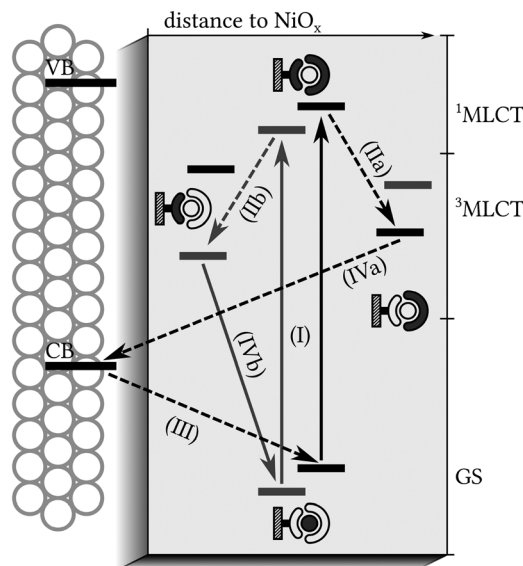


Fig. 6 Energy scheme of transitions on the dye-sensitized NiO_x surfaces for **Ru1** (gray) and **Ru2** (black). After initial excitation (I) to a $^1\text{MLCT}$, localization, intersystem crossing and thermal relaxation to $^3\text{MLCT}$ states occur (II). In the case of **Ru2**, hole injection is observed (III). Subsequently, the systems return to the ground state (IV). Solid arrows indicate radiative and dashed arrows non-radiative transitions. Furthermore, a schematic representation of the localization of the excited state is provided. The dashed square represents the NiO_x surface on which a ligand is or ligands are attached, the round circle visualizes the Ru centre and the half circle the unattached ligand(s). The moiety where the excitation resides within the model discussed in the text is blackened.

groups attached to the ligand. This behaviour in **Ru2** supports hole injection to the semiconductor (III). Finally, recombination (IVa) occurs.

Conclusion

The paper at hand details the ultrafast processes in the structurally related Ru-bipyridine dyes bis[2,2'-bipyridine][4,4'-dicarboxy-2,2'-bipyridine]ruthenium(II) dihexafluorophosphate, [Ru(bpy)₂dcb]-(PF₆)₂ (**Ru1**) and tris[4,4'-bis(ethylcarboxy)-2,2'-bipyridine]-ruthenium(II) dihexafluorophosphate, [Ru(dceb)₃](PF₆)₂ (**Ru2**) on NiO_x nanoparticle films with the specific focus on a detailed investigation of the hole injection dynamics. The binding of the dyes on the NiO_x surface was elucidated using attenuated total reflection-Fourier transform infrared spectroscopy (ATR-FTIR). **Ru1** is bound with both carboxy groups to the NiO_x, while for **Ru2** there is evidence for both bound and free anchor groups, which makes the binding *via* two or three carboxy groups most likely. This implies that at least one bis-ethylcarboxy-bipyridine ligand of **Ru2** is not attached to NiO_x.

Although both dyes exhibit comparable physical and chemical properties, their behaviour on the semiconductor metal oxide surface NiO_x has been evidenced to be very different. Both dyes exhibit similar ground state absorption spectra and the excited state relaxation behaviour in acetonitrile solution shows broad ³MLCT absorption, which does not decay within the temporal window accessible in the experimental setup (2 ns). For **Ru1** the spectral features remain unchanged upon binding on NiO_x nanoparticles. Furthermore, for **Ru1** on NiO_x long-lived luminescence, which decays within 18 ns, is observed. Thus no direct interactions, *i.e.* hole injection from the photoexcited dye **Ru1** to the semiconductor nanoparticles is observed. In contrast to this and despite minor structural changes compared to **Ru1**, photoexcited **Ru2** reveals clear evidence of a hole injection reaction into NiO_x: emission of **Ru2** on NiO_x is effectively quenched and the ultrafast transient absorption spectra show the hole injection with a characteristic time-constant of 18 ps.

This deviant behaviour of the dyes is attributed to the different localization of the initially populated excited state: in case of **Ru1**, the excited state is localized on the dicarboxy-bipyridine, due to the -I effect of the carboxylic groups. Since this is the ligand with which the dye is bound to the NiO_x surface, a hole injection is hindered. Contrarily, for **Ru2** the initially populated excited state is localized on the ester-substituted ligands, which are not bound to the semiconductor surface. Hence, the excess charge density that is abstracted from the Ru-ion in the metal-to-ligand charge-transfer transition is shifted away from the NiO_x surface, which ultimately facilitates hole transfer into the semiconductor.

The results presented in the paper might invoke studies on the role of differently charged linker and anchor units of dyes attached to the NiO_x surface. It might be possible that negatively charged moieties in general inhibit charge injection to NiO_x but more systematic measurements on many different dyes need to be carried out in order to test this hypothesis.

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